

Description

The SVD2955 uses advanced trench

technology to provide excellent R_{DS(ON)}, low gate

charge and operation with gate voltages as low

as 4.5V. This device is suitable for use as a

Battery protection or in other Switching application.



TO-252-2L

General Features

 $V_{DS} = -60V I_{D} = -10 A$

 $R_{DS(ON)}$ < 140m Ω @ V_{GS} =10V

G S S

Application

Brushless motor

Load switch

Uninterruptible power supply

P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
SVD2955	TO-252-2L	HXY MOSFET	2500

Absolute Maximum Ratings (T_c=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units		
V _{DS}	Drain-Source Voltage	-60	V		
Vgs	Gate-Source Voltage	±20	V		
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ -10V ¹	Continuous Drain Current, V _{GS} @ -10V ¹ -10			
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ -10V ¹	-8.3	Α		
Ірм	Pulsed Drain Current ² -26		А		
EAS	Single Pulse Avalanche Energy ³	29.8	mJ		
las	Avalanche Current	-24.4	Α		
$P_D@T_C=25^{\circ}C$	Total Power Dissipation ⁴	31.3	W		
Тѕтс	Storage Temperature Range	-55 to 150	°C		
TJ	Operating Junction Temperature Range	-55 to 150	°C		
Reja	Thermal Resistance Junction-Ambient ¹	62	°C/W		
Rejc	Thermal Resistance Junction-Case ¹	4.0	°C/W		



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =-250uA	-60		-	V
△BV _{DSS} /△T	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =-1mA		-0.049		V/°C
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =-10V , I _D =-8A		125	140	mΩ
	Static Drain-Source On-Resistance	V _{GS} =-4.5V , I _D =-6A		168	210	
V _{GS(th)}	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =-250uA	-1.0		-2.5	V
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	VGS-VDS , ID250UA		5.42		mV/°C
	Drain Source Leakage Current	V _{DS} =-48V , V _{GS} =0V , T _J =25°C			1	uA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =-48V , V _{GS} =0V , T _J =150°C	/ _{GS} =0V , T _J =150°C		5] uA
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V			±100	nA
gfs	Forward Transconductance	V _{DS} =-5V , I _D =-5A		5.8		S
Qg	Total Gate Charge (-4.5V)			5.85		nC
Q _{gs}	Gate-Source Charge	V _{DS} =-20V , V _{GS} =-4.5V , I _D =-5A		2.9		
Q _{gd}	Gate-Drain Charge			1.8		
T _{d(on)}	Turn-On Delay Time			10		
T _r	Rise Time	V_{DD} =-12V , V_{GS} =-10V , R_{G} =3.3 Ω ,		17		ns
T _{d(off)}	Turn-Off Delay Time	I _D =-5A		22		
T _f	Fall Time			21		
C _{iss}	Input Capacitance			715		
Coss	Output Capacitance	V _{DS} =-15V , V _{GS} =0V , F=1MHz		51		pF
C _{rss}	Reverse Transfer Capacitance			34		
Is	Continuous Source Current ^{1,5}	V =V =0V Force Current			-9.5	Α
I _{SM}	Pulsed Source Current ^{2,5}	V _G =V _D =0V , Force Current			-24	Α
V _{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1A , T _J =25°C			-1.2	٧
t _{rr}	Reverse Recovery Time			10.2		nS
Q _{rr}	Reverse Recovery Charge	IF=-8A,dI/dt=100A/μs,T _J =25°C		5.4		nC

Note:

- 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2. The data tested by pulsed , pulse width $\,\leq\,300\text{us}$, duty cycle $\,\leq\,2\%$
- 3. The EAS data shows Max. rating. The test condition is V_{DD} =-25V, V_{GS} =-10V,L=0.1mH, I_{AS} =-15A
- 4. The power dissipation is limited by 150°C junction temperature
- 5. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.

Typical Characteristics

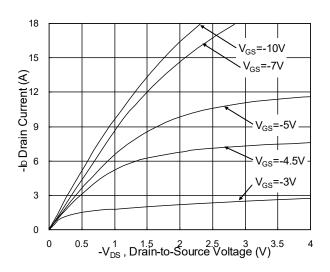


Fig.1 Typical Output Characteristics

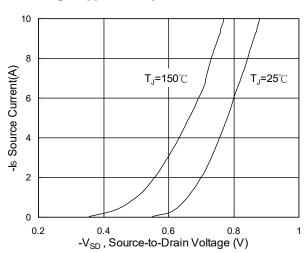


Fig.3 Forward Characteristics Of Reverse

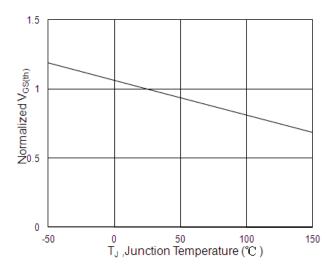


Fig.5 Normalized $V_{\text{GS(th)}}$ vs. T_{J}

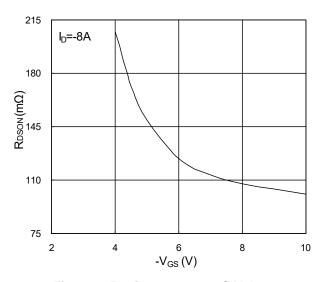


Fig.2 On-Resistance vs. G-S Voltage

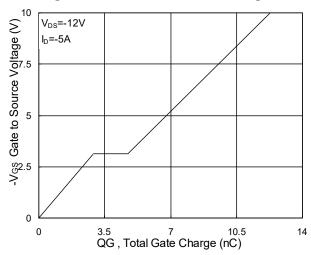


Fig.4 Gate-Charge Characteristics

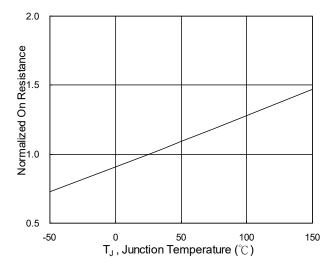
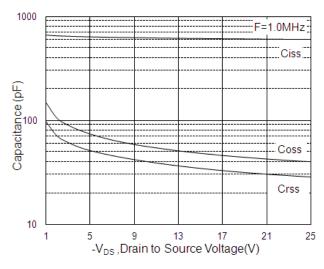


Fig.6 Normalized R_{DSON} vs. T_J



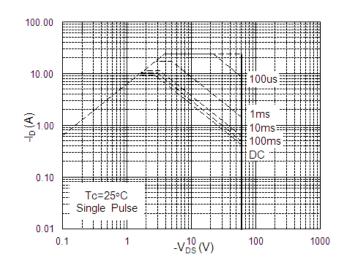


Fig.7 Capacitance

Fig.8 Safe Operating Area

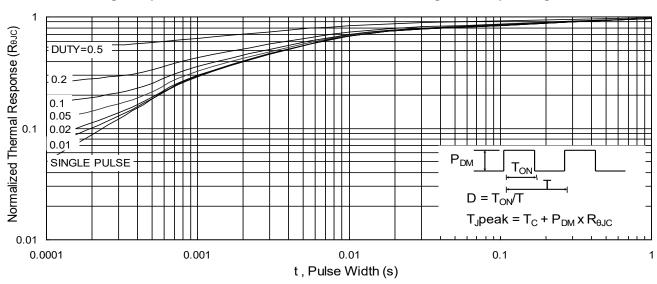
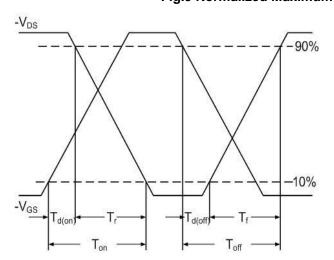


Fig.9 Normalized Maximum Transient Thermal Impedance



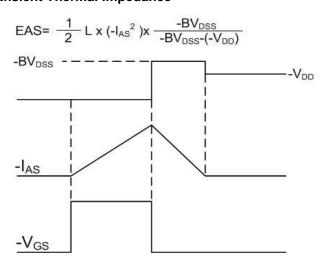
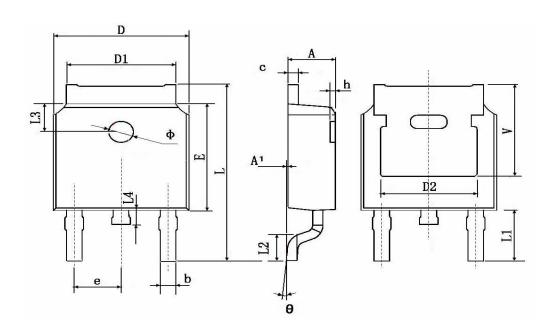


Fig.11 Unclamped Inductive Switching Waveform

TO-252-2L Package Information



Dimensions In Millimeters		Dimensions In Inches		
Min.	Max.	Min.	Max.	
2.200	2.400	0.087	0.094	
0.000	0.127	0.000	0.005	
0.660	0.860	0.026	0.034	
0.460	0.580	0.018	0.023	
6.500	6.700	0.256	0.264	
5.100	5.460	0.201	0.215	
4.830 TYP.		0.190 TYP.		
6.000	6.200	0.236	0.244	
2.186	2.386	0.086	0.094	
9.800	10.400	0.386	0.409	
2.900 TYP.		0.114 TYP.		
1 400	1 700	0.055	0.067	
		0.063 TYP.		
0.600	1.000	0.024	0.039	
1.100	1.300	0.043	0.051	
0°	8°	0°	8°	
0.000	0.300	0.000	0.012	
5.350 TYP.		0.211 TYP.		
	Min. 2.200 0.000 0.660 0.460 6.500 5.100 4.830 6.000 2.186 9.800 2.900 1.400 1.600 0.600 1.100 0° 0.000	Min. Max. 2.200 2.400 0.000 0.127 0.660 0.860 0.460 0.580 6.500 6.700 5.100 5.460 4.830 TYP. 6.200 2.186 2.386 9.800 10.400 2.900 TYP. 1.700 1.600 TYP. 0.600 1.100 1.300 0° 8° 0.000 0.300	Min. Max. Min. 2.200 2.400 0.087 0.000 0.127 0.000 0.660 0.860 0.026 0.460 0.580 0.018 6.500 6.700 0.256 5.100 5.460 0.201 4.830 TYP. 0.190 6.000 6.200 0.236 2.186 2.386 0.086 9.800 10.400 0.386 2.900 TYP. 0.114 1.400 1.700 0.055 1.600 TYP. 0.063 0.600 1.000 0.024 1.100 1.300 0.043 0° 8° 0° 0.000 0.300 0.000	



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